

TOSHIBA Field-Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

## SSM3J334R

### Power Management Switch Applications

- Low ON-resistance:  $R_{DS(ON)} = 71 \text{ m}\Omega$  (max) (@ $V_{GS} = -10 \text{ V}$ )  
 $R_{DS(ON)} = 105 \text{ m}\Omega$  (max) (@ $V_{GS} = -4.5 \text{ V}$ )  
 $R_{DS(ON)} = 136 \text{ m}\Omega$  (max) (@ $V_{GS} = -4.0 \text{ V}$ )

### Absolute Maximum Ratings (Ta = 25°C)

| Characteristic            | Symbol         | Rating              | Unit |
|---------------------------|----------------|---------------------|------|
| Drain-Source voltage      | $V_{DSS}$      | -30                 | V    |
| Gate-Source voltage       | $V_{GSS}$      | $\pm 20$            | V    |
| Drain current             | DC             | $I_D$ (Note 1)      | -4   |
|                           | Pulse          | $I_{DP}$ (Note 1,2) | -16  |
| Power dissipation         | $P_D$ (Note 3) | $t < 10\text{s}$    | 1    |
|                           |                |                     | 2    |
| Channel temperature       | $T_{ch}$       | 150                 | °C   |
| Storage temperature range | $T_{stg}$      | -55 to 150          | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

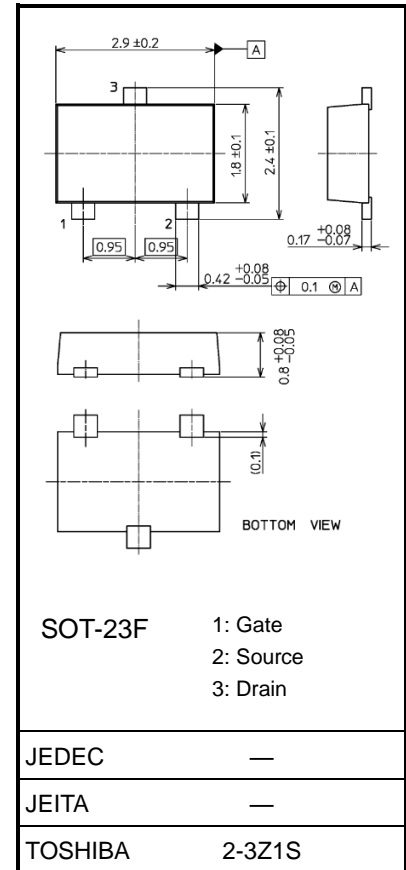
Note 1: The channel temperature should not exceed 150°C during use.

Note 2:  $PW \leq 1\text{ms}$ , Duty  $\leq 1\%$

Note 3: Mounted on a FR4 board.

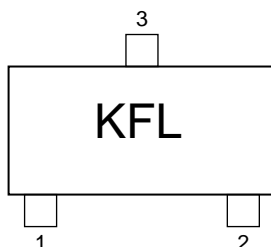
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

Unit: mm

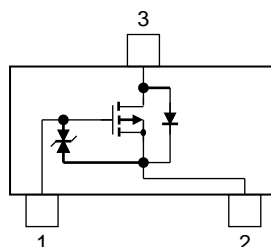


Weight: 11 mg (typ.)

### Marking



### Equivalent Circuit (Top View)



Start of commercial production  
2010-08

## Electrical Characteristics (Ta = 25°C)

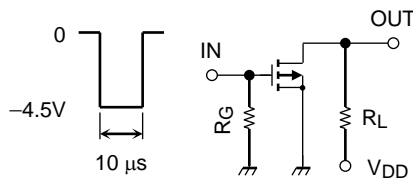
| Characteristic                 | Symbol        | Test Conditions                          | Min  | Typ. | Max  | Unit |
|--------------------------------|---------------|--|--|------|------|------|
| Drain-Source breakdown voltage | V (BR) DSS    | ID = -10 mA, VGS = 0 V                   | -30  | —    | —    | V    |
|                                | V (BR) DSX    | ID = -10 mA, VGS = 10 V (Note 5)         | -21  | —    | —    | V    |
| Drain cut-off current          | IDSS          | VDS = -30 V, VGS = 0 V                   | —  | —    | -1   | μA   |
| Gate leakage current           | IGSS          | VGS = ±16 V, VDS = 0 V                   | —  | —    | ±10  | μA   |
| Gate threshold voltage         | Vth           | VDS = -10 V, ID = -100 μA                | -0.8   | —    | -2.0 | V    |
| Forward transfer admittance    | Yfs           | VDS = -10 V, ID = -1.0 A (Note 4)        | 2.3  | 4.6  | —    | S    |
| Drain-source ON-resistance     | RDS (ON)      | ID = -3.0 A, VGS = -10 V (Note 4)        | —  | 54   | 71   | mΩ   |
|                                |               | ID = -2.0 A, VGS = -4.5 V (Note 4)       | —  | 80   | 105  |      |
|                                |               | ID = -1.0 A, VGS = -4.0 V (Note 4)       | —  | 89   | 136  |      |
| Input capacitance              | Ciss          | VDS = -15 V, VGS = 0 V<br>f = 1 MHz      | —  | 280  | —    | pF   |
| Output capacitance             | Coss          |  | —  | 55   | —    |      |
| Reverse transfer capacitance   | Crss          |  | —  | 40   | —    |      |
| Switching time                 | Turn-on time  | ton                                      | VDD = -15 V, ID = -1.0 A<br>VGS = 0 to -4.5 V, RG = 10 Ω | —    | 13   | ns   |
|                                | Turn-off time | toff                                     |  | —    | 22   |      |
| Total Gate Charge              | Qg            | VDD = -15 V, ID = -4.0 A,<br>VGS = -10 V | —  | 5.9  | —    | nC   |
| Gate-Source Charge             | Qgs1          |  | —  | 0.8  | —    |      |
| Gate-Drain Charge              | Qgd           |  | —  | 1.2  | —    |      |
| Drain-Source forward voltage   | VDSF          | ID = 4.0 A, VGS = 0 V (Note 4)           | —  | 0.9  | 1.2  | V    |

Note4: Pulse test

Note5: If a forward bias is applied between gate and source, this device enters V(BR)DSX mode. Note that the drain-source breakdown voltage is lowered in this mode.

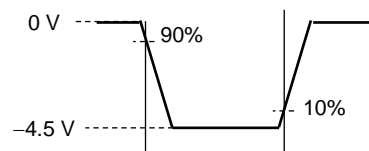
## Switching Time Test Circuit

### (a) Test Circuit

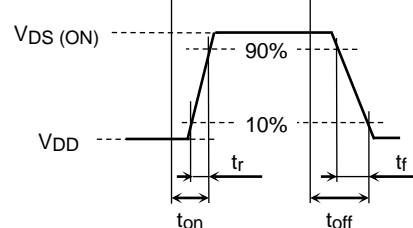


VDD = -15 V  
 RG = 10 Ω  
 Duty ≤ 1%  
 VIN: tr, tf < 5 ns  
 Common Source  
 Ta = 25°C

### (b) VIN



### (c) VOUT



## Notice on Usage

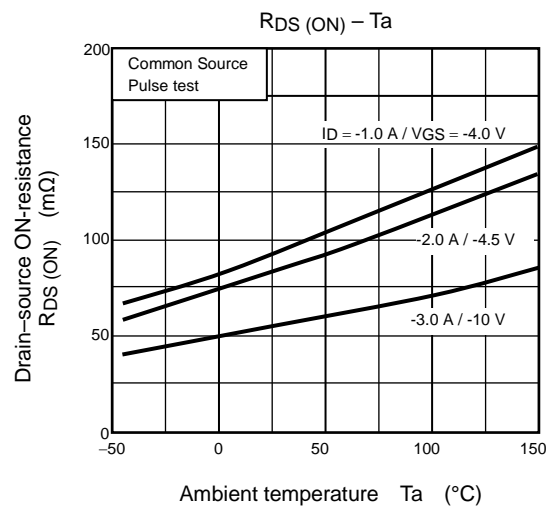
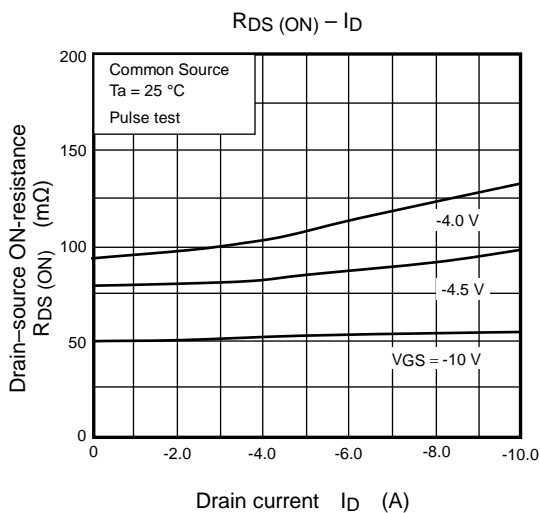
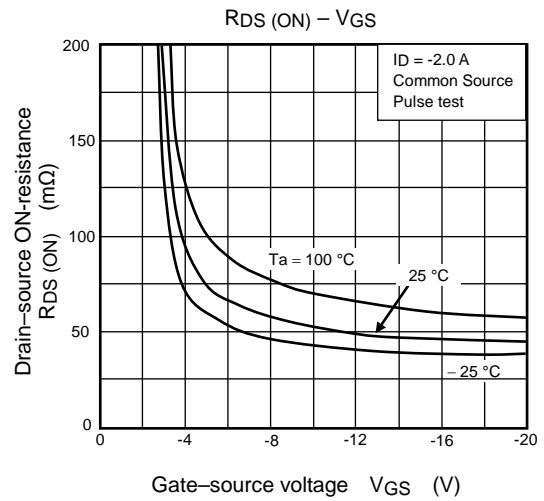
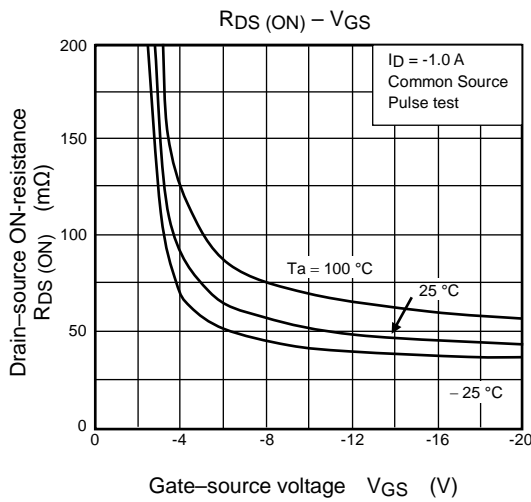
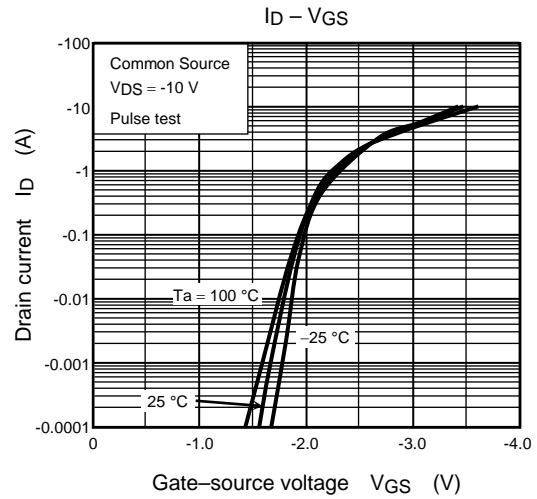
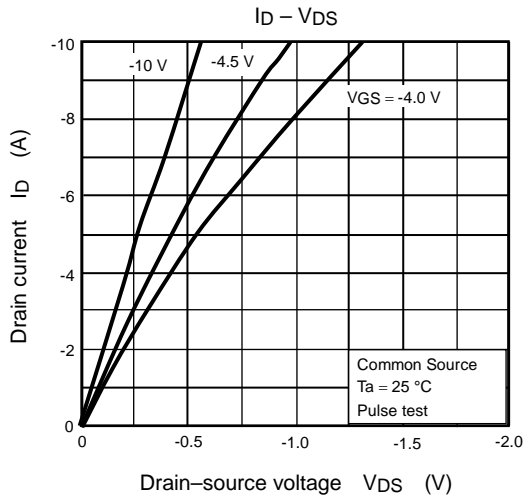
Let Vth be the voltage applied between gate and source that causes the drain current (ID) to be low (-100μA for the SSM3J334R). Then, for normal switching operation, VGS(on) must be higher than Vth, and VGS(off) must be lower than Vth. This relationship can be expressed as: VGS(off) < Vth < VGS(on).

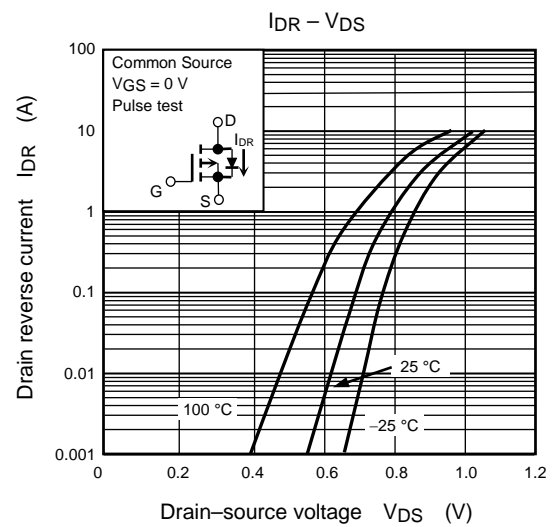
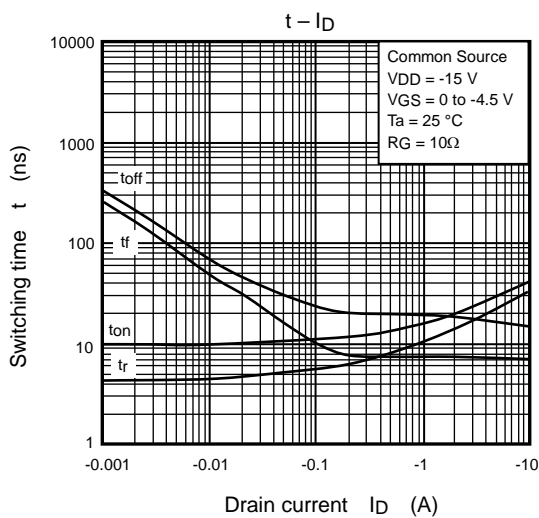
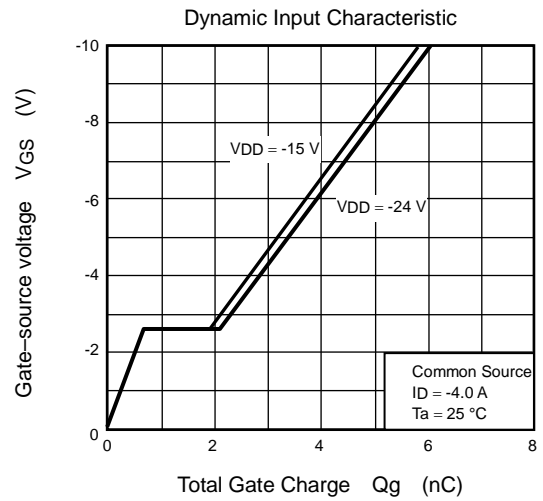
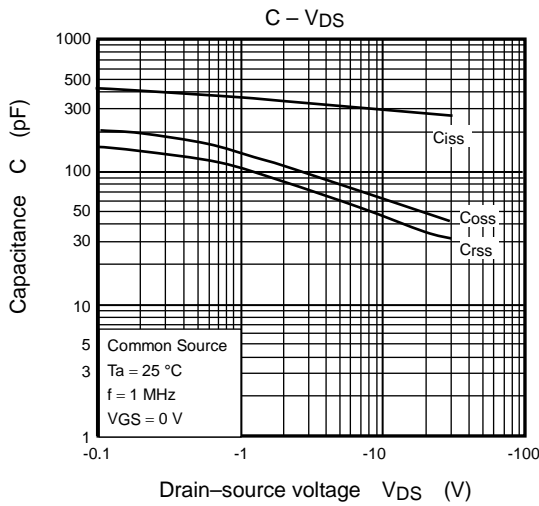
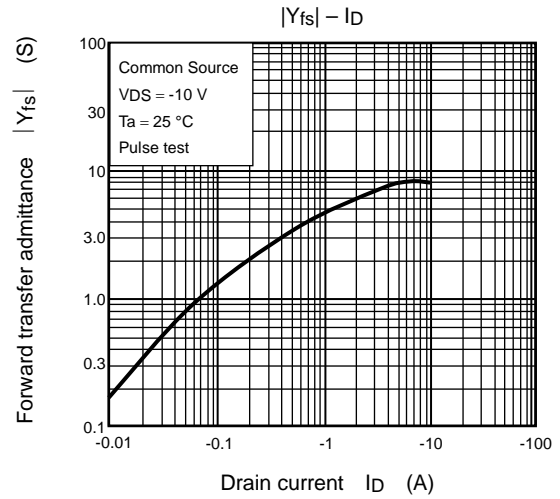
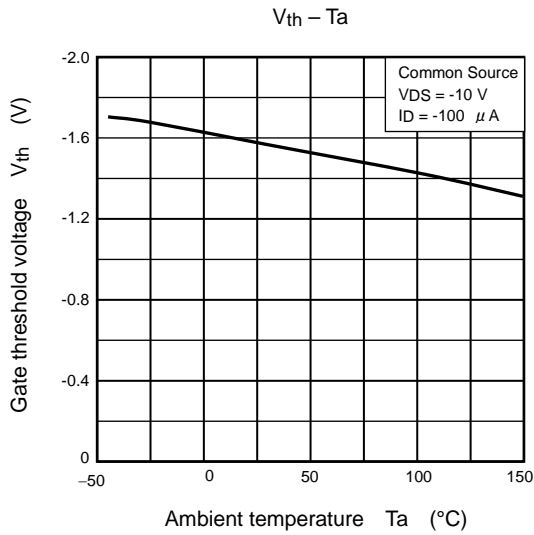
Take this into consideration when using the device.

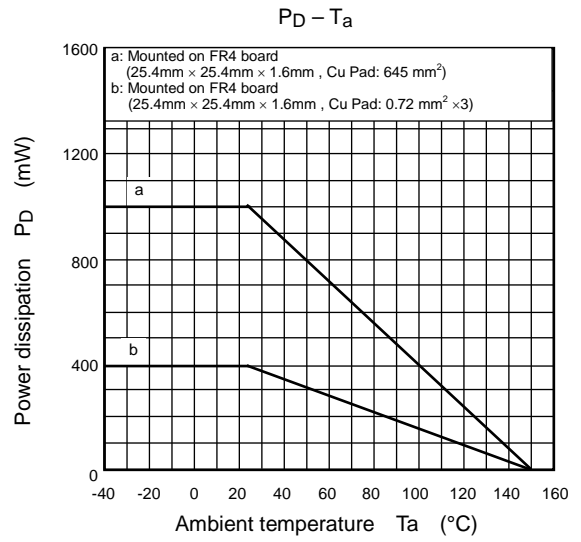
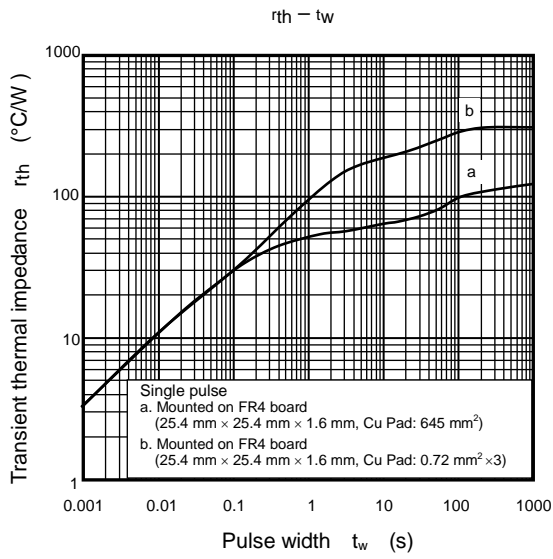
## Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance Rth(ch-a) and power dissipation PD vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration







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